

TPS775xx with $\overline{\text{RESET}}$ Output, TPS776xx with PG Output FAST-TRANSIENT-RESPONSE 500mA LOW-DROPOUT VOLTAGE REGULATORS

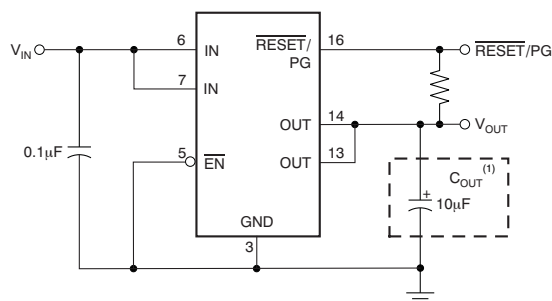
FEATURES

- Open Drain Power-On Reset with 200ms Delay (TPS775xx)
- Open Drain Power Good (TPS776xx)
- 500mA Low-Dropout Voltage Regulator
- Available in Fixed Output and Adjustable Versions
- Dropout Voltage to 169mV (Typ) at 500mA (TPS77x33)
- Ultralow 85µA Typical Quiescent Current
- Fast Transient Response
- 2% Tolerance Over Specified Conditions for Fixed-Output Versions
- 8-Pin SOIC and 20-Pin TSSOP PowerPAD™ (PWP) Packages
- Thermal Shutdown Protection

APPLICATIONS

- FPGA Power
- DSP Core and I/O Voltages

**Typical Application Circuit
(Fixed Voltage Options)**



DESCRIPTION

The TPS775xx and TPS776xx devices are designed to have a fast transient response and be stable with a 10µF low ESR capacitor. This combination provides high performance at a reasonable cost.

Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (typically 169mV at an output current of 500mA for the TPS77x33) and is directly proportional to the output current. Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and independent of output loading (typically 85µA over the full range of output current, 0mA to 500mA). These two key specifications yield a significant improvement in operating life for battery-powered systems. This LDO family also features a sleep mode; applying a TTL high signal to $\overline{\text{EN}}$ (enable) shuts down the regulator, reducing the quiescent current to 1µA at $T_J = +25^\circ\text{C}$.

The $\overline{\text{RESET}}$ output of the TPS775xx initiates a reset in microcomputer and microprocessor systems in the event of an undervoltage condition. An internal comparator in the TPS775xx monitors the output voltage of the regulator to detect an undervoltage condition on the regulated output voltage.

Power good (PG) of the TPS776xx is an active high output, which can be used to implement a power-on reset or a low-battery indicator.

The TPS775xx and TPS776xx are offered in 1.5V, 1.6V (TPS77516 only), 1.8V, 2.5V, 2.8V (TPS77628 only), and 3.3V fixed-voltage versions and in an adjustable version (programmable over the range of 1.5V to 5.5V for the TPS77501 and 1.2V to 5.5V for the TPS77601). Output voltage tolerance is specified as a maximum of 2% over line, load, and temperature ranges. The TPS775xx and TPS776xx families are available in 8-pin SOIC and 20-pin TSSOP packages.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾

PRODUCT	V _{OUT} ⁽²⁾
TPS775xxyyyz, TPS776xxyyyz	XX is nominal output voltage (for example, 28 = 2.8V, 285 = 2.85V, 01 = Adjustable). YYY is package designator. Z is package quantity.

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) Custom fixed output voltages are available; minimum order quantities may apply. Contact factory for details and availability.

ABSOLUTE MAXIMUM RATINGS

Over operating temperature range (unless otherwise noted)⁽¹⁾

PARAMETER	TPS775xx, TPS776xx	UNIT
Input voltage range, V _{IN} ⁽²⁾	–0.3 to +13.5	V
Voltage range at $\overline{\text{EN}}$	–0.3 to +16.5	V
Maximum $\overline{\text{RESET}}$ voltage (TPS775xx)	16.5	V
Maximum PG voltage (TPS776xx)	16.5	V
Peak output current	Internally limited	
Voltage range at OUT, FB	7	V
Continuous total power dissipation	See Dissipation Ratings Table	
Operating junction temperature range, T _J	–40 to +125	°C
Storage junction temperature range, T _{STG}	–65 to +150	°C
ESD rating, HBM	2	kV

(1) Stresses above these ratings may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) All voltages are with respect to network terminal ground.

DISSIPATION RATINGS

BOARD	PACKAGE	AIRFLOW (CFM)	T _A < +25°C	DERATING FACTOR ABOVE T _A = +25°C	T _A = +70°C	T _A = +85°C
—	D	0	568mW	5.68mW/°C	312mW	227mW
		250	904mW	9.04mW/°C	497mW	361mW
Low-K ⁽¹⁾	PWP	0	2.9mW	23.5mW/°C	1.9W	1.5W
		300	4.3mW	34.6mW/°C	2.8W	2.2W
High-K ⁽²⁾	PWP	0	3W	23.8mW/°C	1.9W	1.5W
		300	7.2W	57.9mW/°C	4.6W	3.8W

(1) This parameter is measured with the recommended copper heat sink pattern on a 1-layer, 5in x5in printed circuit board (PCB), 1-ounce copper, 2in x2in coverage (4in²).

(2) This parameter is measured with the recommended copper heat sink pattern on a 8-layer, 1.5in x2in PCB, 1-ounce copper with layers 1, 2, 4, 5, 7, and 8 at 5% coverage (0.9in²) and layers 3 and 6 at 100% coverage (6in²). For more information, refer to TI technical brief [SLMA002](#).

ELECTRICAL CHARACTERISTICS

Over recommended operating temperature range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$), $V_{IN} = V_{OUT(TYP)} + 1\text{V}$; $I_{OUT} = 1\text{mA}$, $V_{EN} = 0\text{V}$, $C_{OUT} = 10\mu\text{F}$, unless otherwise noted. Typical values are at $T_J = +25^{\circ}\text{C}$.

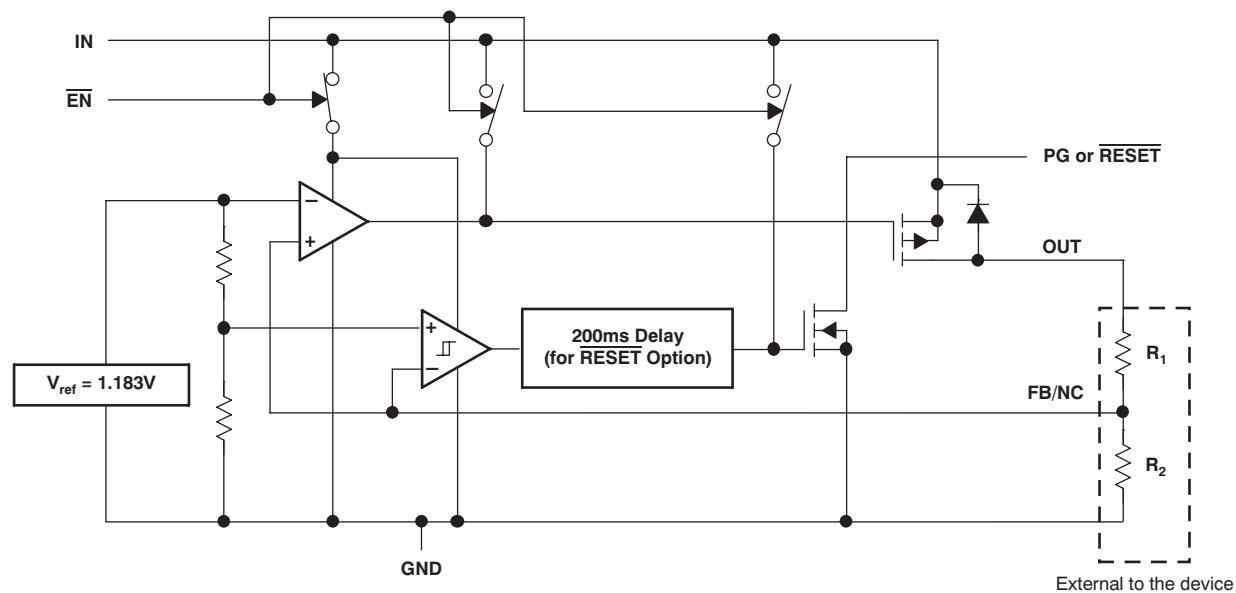
PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IN}	Input voltage range			2.7		10	V
V_{OUT}	Output voltage range	TPS77501		1.5		5.5	V
		TPS77601		1.2		5.5	V
V_{OUT}	Accuracy		$V_{OUT} + 1\text{V} \leq V_{IN} \leq 10\text{V}^{(1)}$ $10\mu\text{A} < I_{OUT} < 500\text{mA}$	-2.0		+2.0	%
I_{GND}	Ground pin current		$I_{OUT} = 10\text{mA}$		85		μA
			$I_{OUT} = 500\text{mA}$			125	
$\Delta V_{OUT}\% / \Delta V_{IN}$	Output voltage line regulation		$V_{OUT} + 1\text{V} \leq V_{IN} \leq 10\text{V}^{(1)}$		0.01		%/V
$\Delta V_{OUT}\% / \Delta I_{OUT}$	Load regulation				3		mV
V_N	Output noise voltage BW = 200Hz to 100kHz	TPS77x18	$I_C = 500\text{mA}$, $C_{OUT} = 10\mu\text{F}$		53		μV_{RMS}
V_{DO}	Dropout voltage ⁽²⁾	TPS77628	$I_{OUT} = 500\text{mA}$		285	410	mV
		TPS77533	$I_{OUT} = 500\text{mA}$		169	287	mV
		TPS77633	$I_{OUT} = 500\text{mA}$		169	287	mV
I_{CL}	Output current limit		$V_{OUT} = 0\text{V}$	1.2	1.6	1.9	A
T_{SD}	Shutdown temperature				150		$^{\circ}\text{C}$
T_J	Operating junction temperature range			-40		+125	$^{\circ}\text{C}$
I_{STBY}	Standby current		$\overline{\text{EN}} = V_{IN}$, at $T_J = +25^{\circ}\text{C}$, $2.7\text{V} < V_{IN} < 10\text{V}$		1		μA
			$\overline{\text{EN}} = V_{IN}$, $2.7\text{V} < V_{IN} < 10\text{V}$			10	
I_{FB}	FB input current	TPS77x01	FB = 1.5V		2		nA
$V_{EN(HI)}$	High-level enable input voltage			1.7			V
$V_{EN(LO)}$	Low-level enable input voltage					0.9	V
PSRR	Power-supply ripple rejection		$f = 100\text{Hz}$, $C_{OUT} = 10\mu\text{F}$		60		dB
RESET (TPS775xx)	Minimum input voltage for valid RESET		$I_{OUT(RESSET)} = 300\mu\text{A}$		1.1		V
	Trip threshold voltage		V_{OUT} decreasing	92		98	% V_{OUT}
	Hysteresis voltage		Measured at V_{OUT}		0.5		% V_{OUT}
	Output low voltage		$V_{IN} = 2.7\text{V}$, $I_{OUT(RESSET)} = 1\text{mA}$		0.15	0.4	V
	Leakage current		$V_{(RESET)} = 5\text{V}$			1	μA
	RESET time-out delay				200		ms
PG (TPS776xx)	Minimum input voltage for valid PG		$I_{OUT(PG)} = 300\mu\text{A}$		1.1		V
	Trip threshold voltage		V_{OUT} decreasing	92		98	% V_{OUT}
	Hysteresis voltage		Measured at V_{OUT}		0.5		% V_{OUT}
	Output low voltage		$V_{IN} = 2.7\text{V}$, $I_{OUT(PG)} = 1\text{mA}$		0.15	0.4	V
	Leakage current		$V_{(PG)} = 5\text{V}$			1	μA
	Input current ($\overline{\text{EN}}$)		$\overline{\text{EN}} = 0\text{V}$	-1	0	1	μA
			$\overline{\text{EN}} = V_{IN}$	-1		1	

(1) Minimum $V_{IN} = V_{OUT} + V_{DO}$ or 2.7V, whichever is greater.

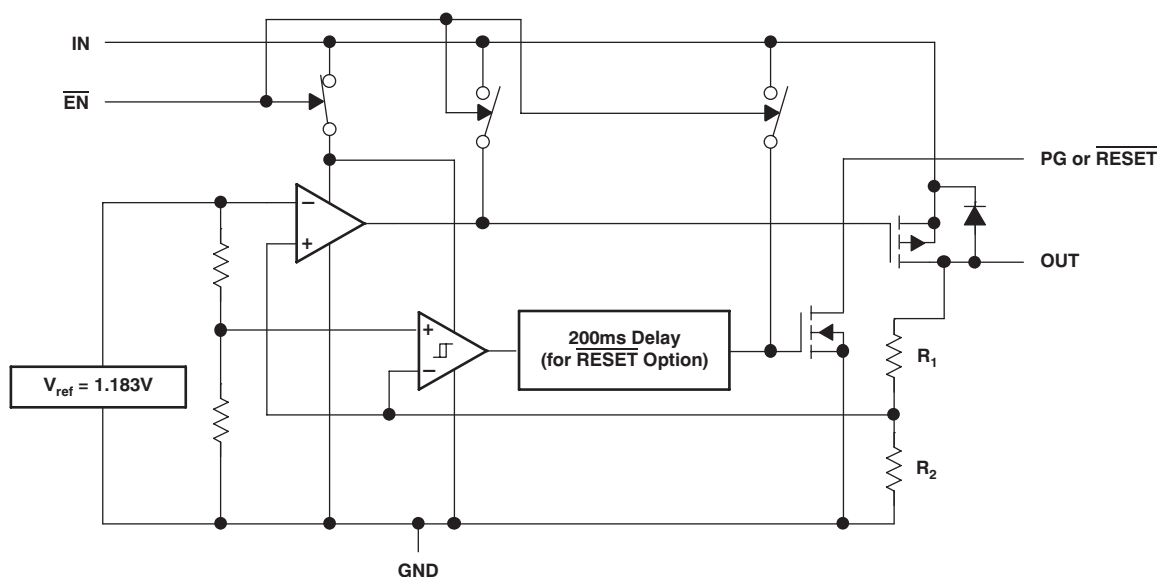
(2) V_{DO} is not measured for fixed output versions with $V_{OUT(NOM)} < 2.8\text{V}$ because minimum $V_{IN} = 2.7\text{V}$.

FUNCTIONAL BLOCK DIAGRAMS

Adjustable Voltage Versions



Fixed Voltage Versions



PIN CONFIGURATIONS

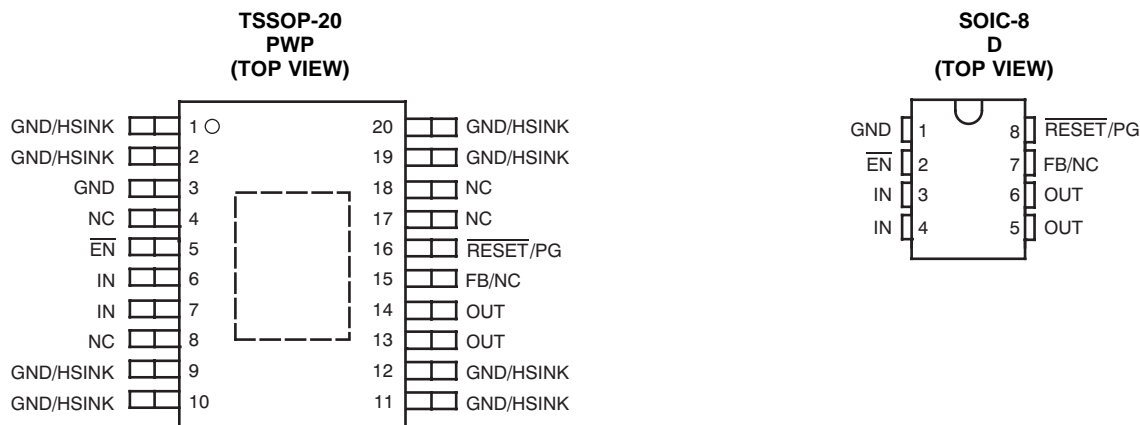
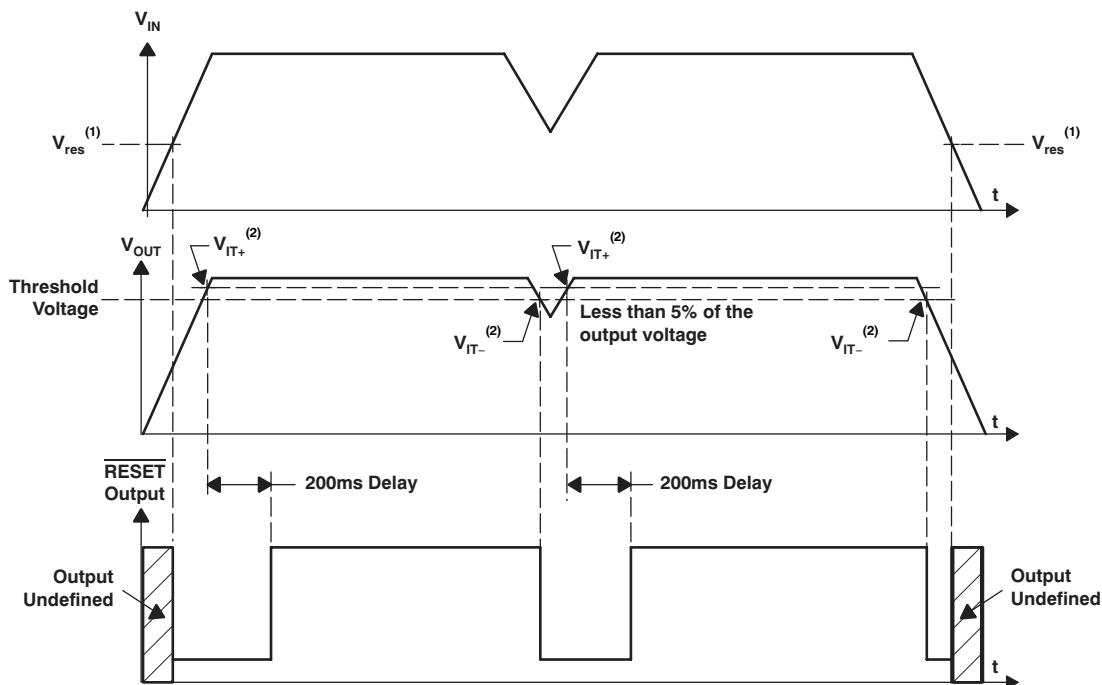


Table 1. PIN DESCRIPTIONS

TPS775xx, TPS776xx			DESCRIPTION
NAME	SOIC-8 (D) PIN NO.	TSSOP-20 (PWP) PIN NO.	
$\overline{\text{EN}}$	2	5	Negative polarity enable ($\overline{\text{EN}}$) input
FB	7	15	Adjustable voltage version only; feedback voltage for setting output voltage of the device. Not internally connected on adjustable versions.
GND	1	1, 2, 3, 9, 10, 11, 12, 19, 20	Ground
IN	3, 4	6, 7	Input voltage
OUT	5, 6	13, 14	Regulated output voltage
$\overline{\text{RESET}}$	8	16	TPS775xx devices only; open-drain $\overline{\text{RESET}}$ output.
PG	8	16	TPS776xx devices only; open-drain power-good (PG) output.
NC	—	4, 8, 17, 18	No internal connection
PAD/TAB	—	—	Should be soldered to ground plane and used for heat sinking.

TPS775xx $\overline{\text{RESET}}$ Timing Diagram



- (1) V_{res} is the minimum input voltage for a valid $\overline{\text{RESET}}$. The symbol V_{res} is not currently listed within EIA or JEDEC standards for semiconductor symbology.
- (2) V_{IT} : Trip voltage is typically 5% lower than the output voltage (95% V_{OUT}). V_{IT-} to V_{IT+} is the hysteresis voltage.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE NO.
V_{OUT}	Output Voltage	vs Output Current	Figure 3, Figure 4, Figure 5
		vs Free-Air Temperature	Figure 6, Figure 7, Figure 8
		vs Time	Figure 20
I_{GND}	Ground Current	vs Free-Air Temperature	Figure 9
PSRR	Power-Supply Ripple Rejection	vs Frequency	Figure 10
	Output Spectral Noise Density	vs Frequency	Figure 11
Z_{OUT}	Output Impedance	vs Frequency	Figure 12
V_{DO}	Dropout Voltage	vs Input Voltage	Figure 13
		vs Free-Air Temperature	Figure 14
V_{IN}	Input Voltage (Min)	vs Output Voltage	Figure 15
LINE	Line Transient Response		Figure 16, Figure 18
LOAD	Load Transient Response		Figure 17, Figure 19
ESR	Equivalent Series Resistance	vs Output Current	Figure 22, Figure 23

TYPICAL CHARACTERISTICS

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$) unless otherwise noted. Typical values are at $T_J = +25^\circ\text{C}$.

TPS77x33
OUTPUT VOLTAGE
vs OUTPUT CURRENT

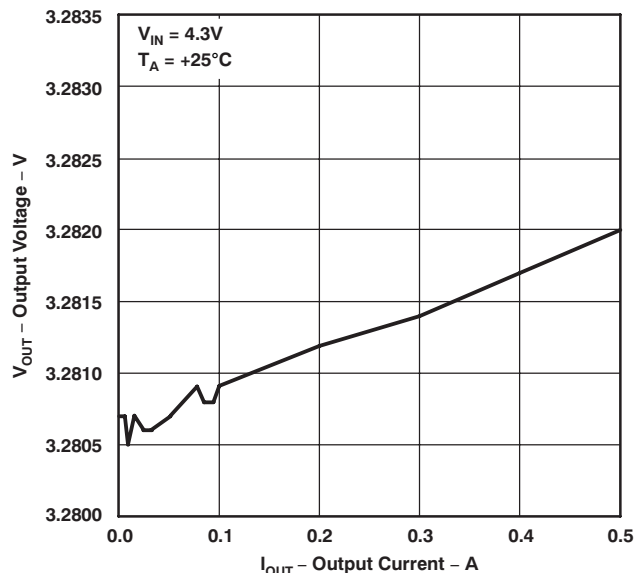


Figure 3.

TPS77x15
OUTPUT VOLTAGE
vs OUTPUT CURRENT

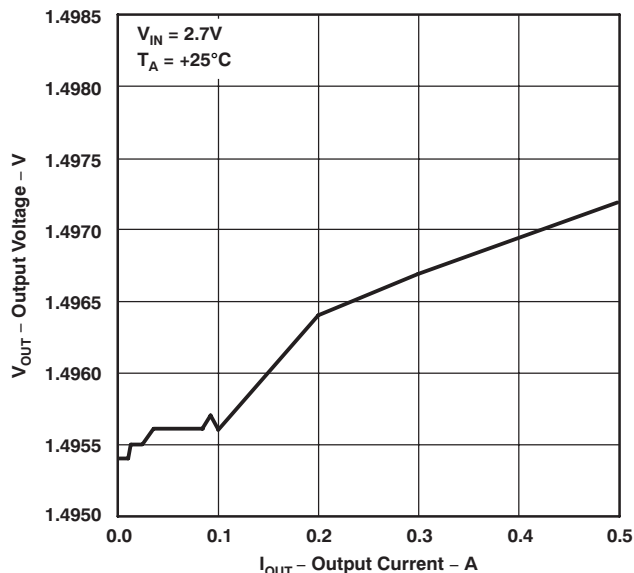


Figure 4.

TPS77x25
OUTPUT VOLTAGE
vs OUTPUT CURRENT

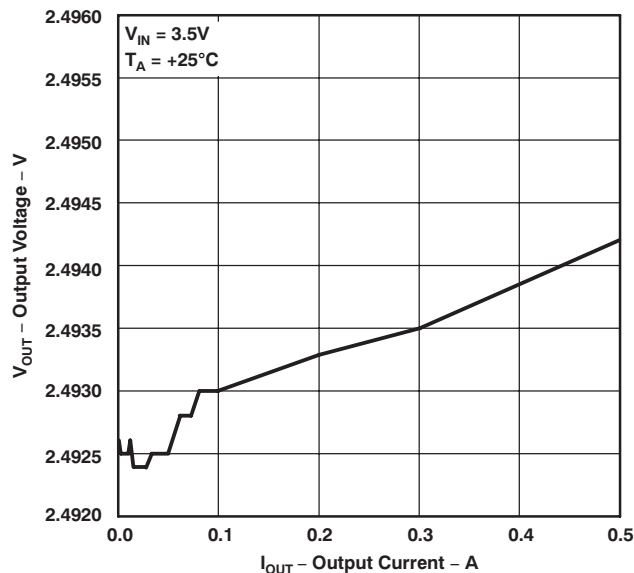


Figure 5.

TPS77x33
OUTPUT VOLTAGE
vs FREE-AIR TEMPERATURE

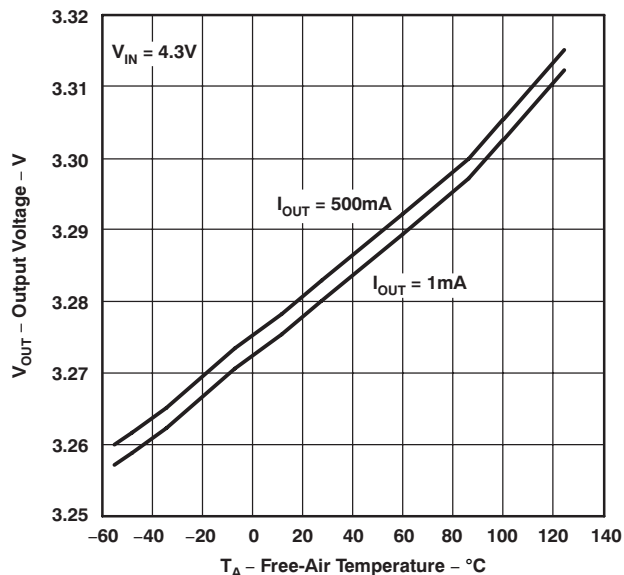


Figure 6.

TYPICAL CHARACTERISTICS (continued)

Over operating temperature range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$) unless otherwise noted. Typical values are at $T_J = +25^{\circ}\text{C}$.

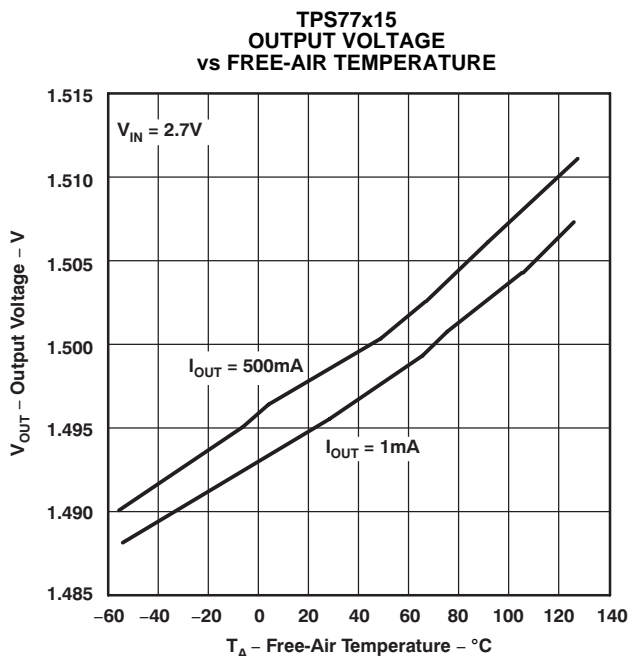


Figure 7.

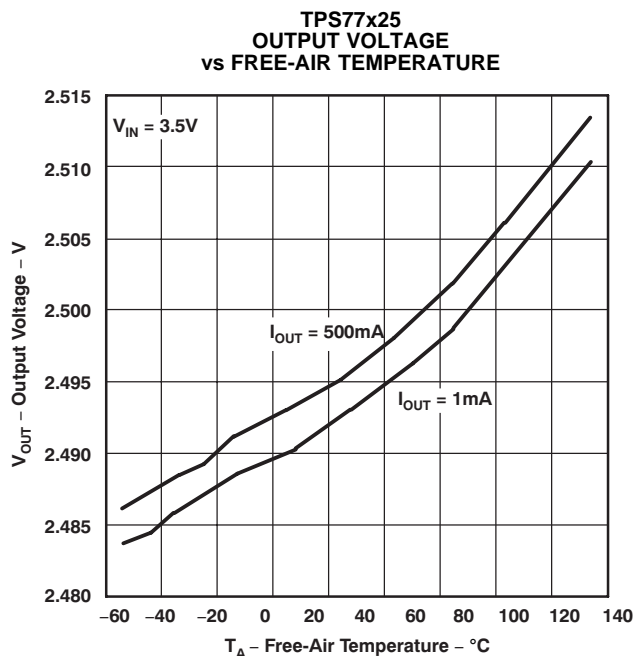


Figure 8.

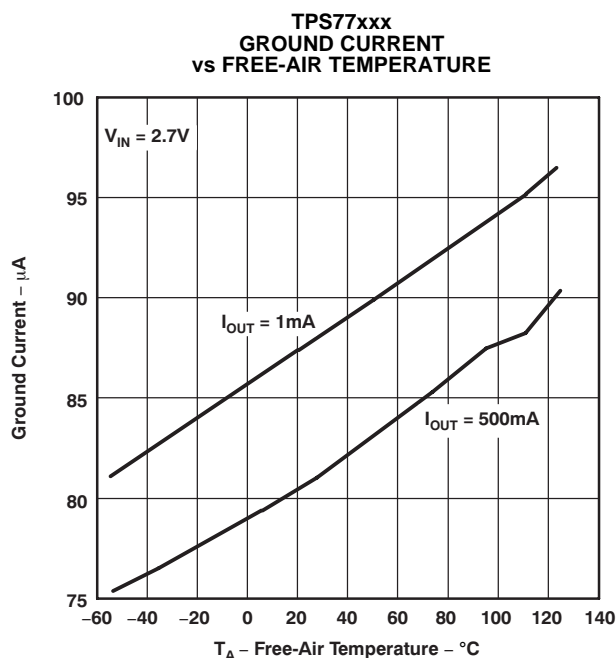


Figure 9.

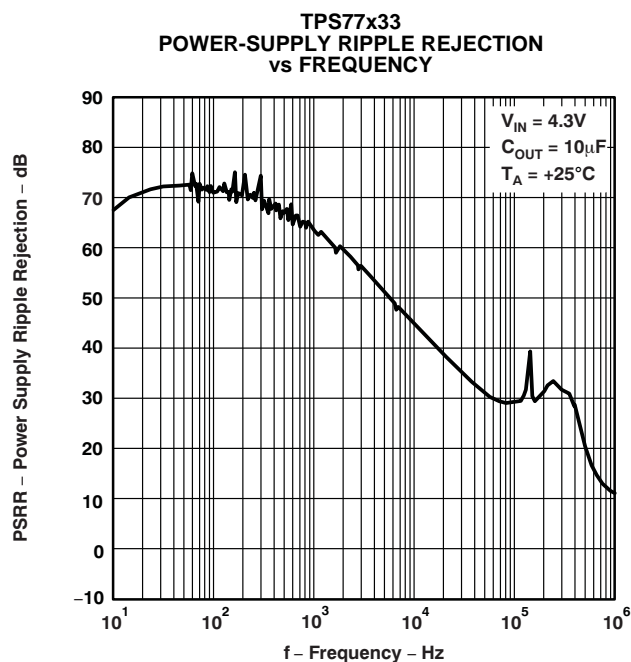


Figure 10.

TYPICAL CHARACTERISTICS (continued)

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$) unless otherwise noted. Typical values are at $T_J = +25^\circ\text{C}$.

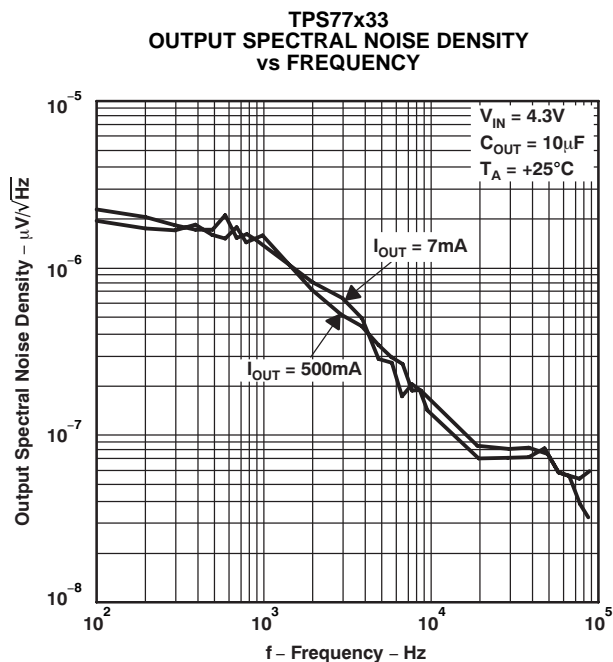


Figure 11.

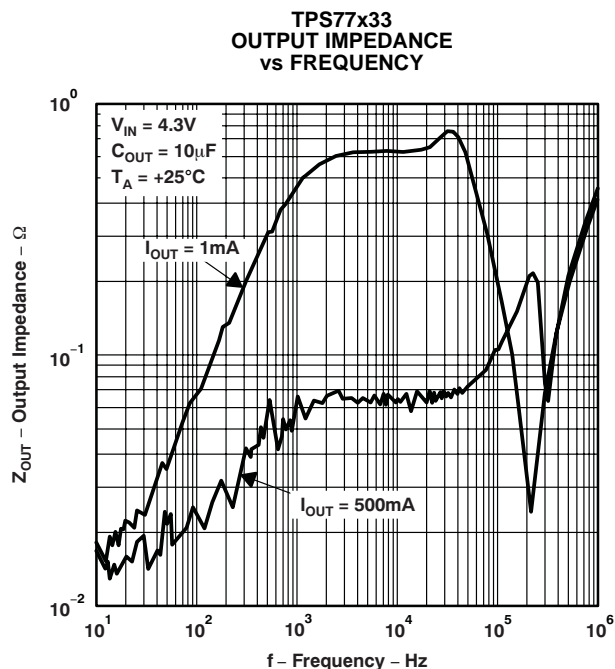


Figure 12.

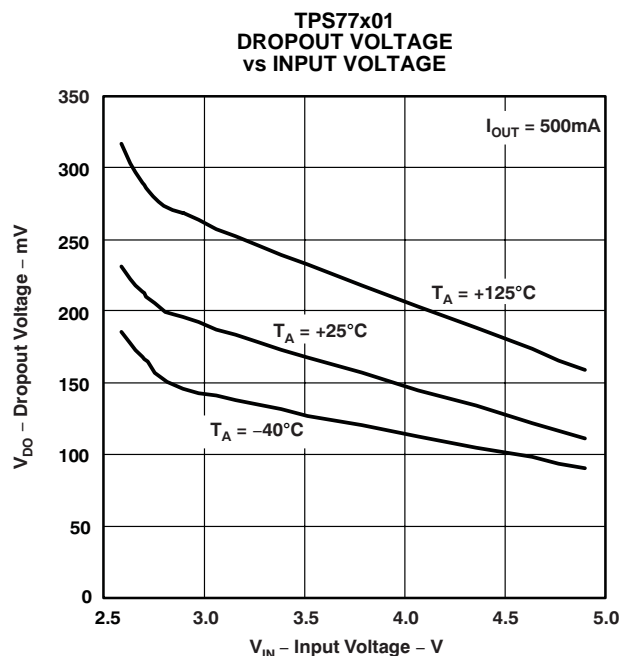


Figure 13.

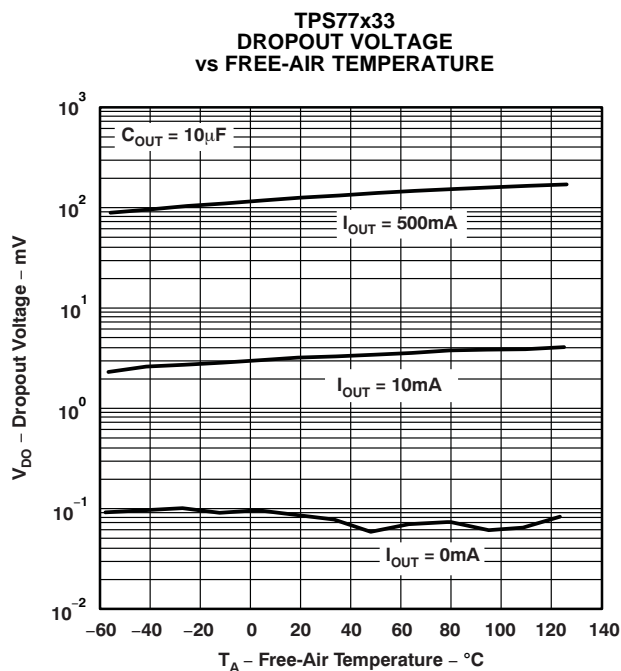
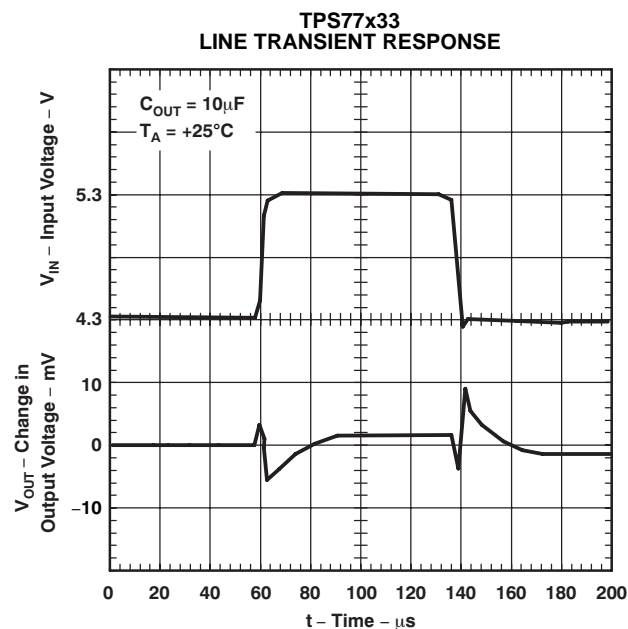
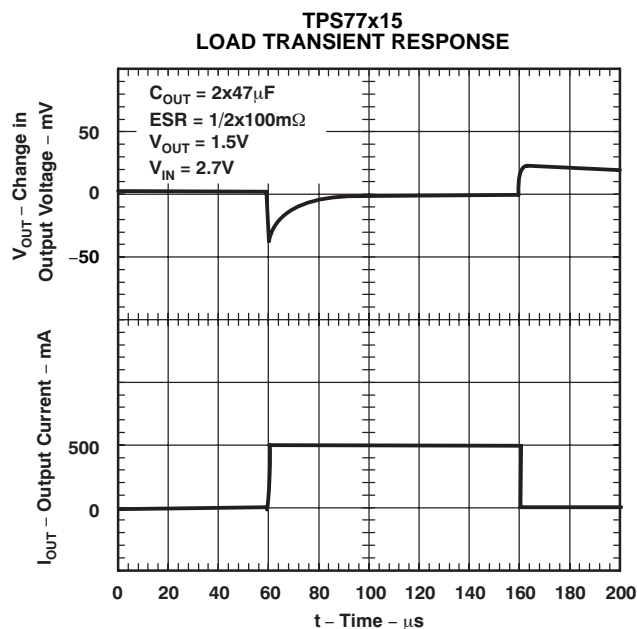
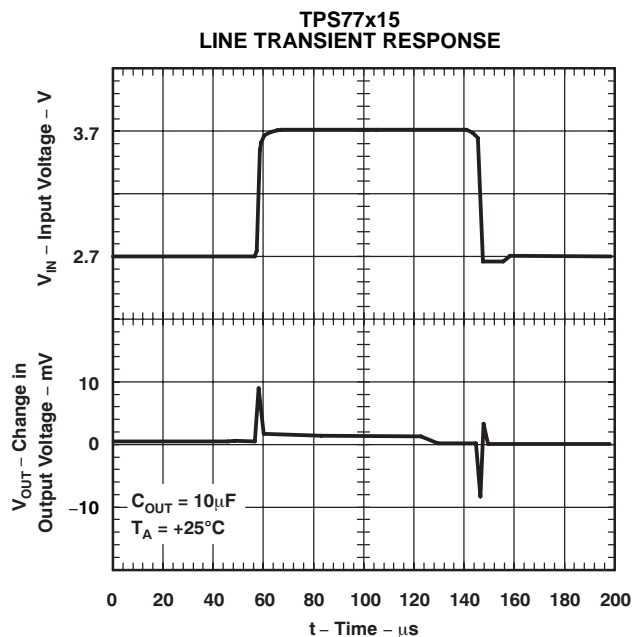
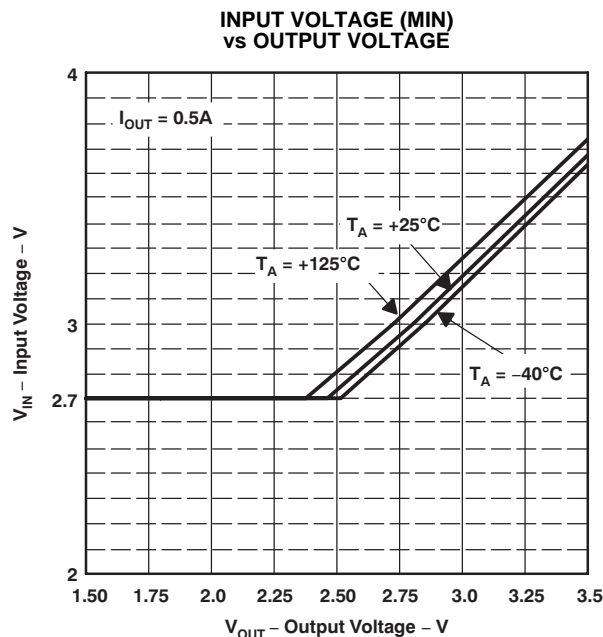


Figure 14.

TYPICAL CHARACTERISTICS (continued)

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$) unless otherwise noted. Typical values are at $T_J = +25^\circ\text{C}$.



TYPICAL CHARACTERISTICS (continued)

Over operating temperature range ($T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$) unless otherwise noted. Typical values are at $T_J = +25^{\circ}\text{C}$.

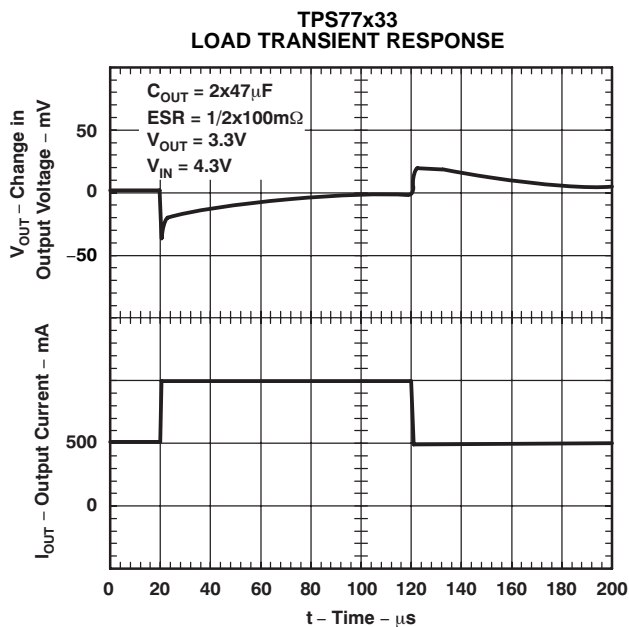


Figure 19.

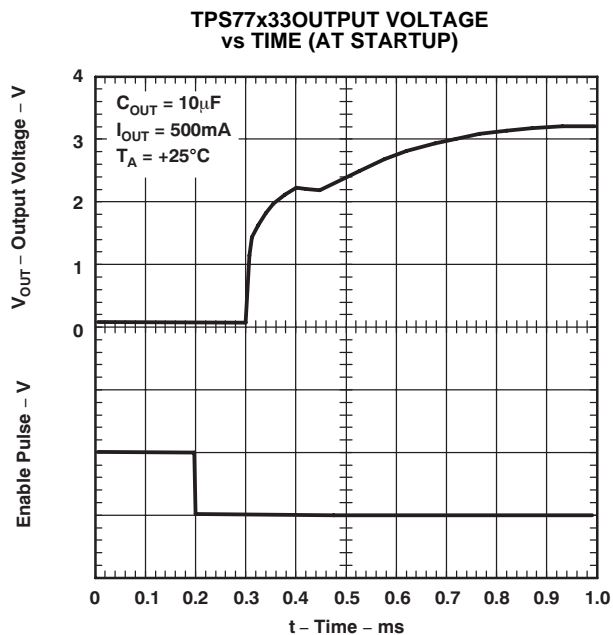


Figure 20.

TYPICAL CHARACTERISTICS (continued)

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$) unless otherwise noted. Typical values are at $T_J = +25^\circ\text{C}$.

Test Circuit for Typical Regions of Stability (Figure 22 and Figure 23) (Fixed Output Options)

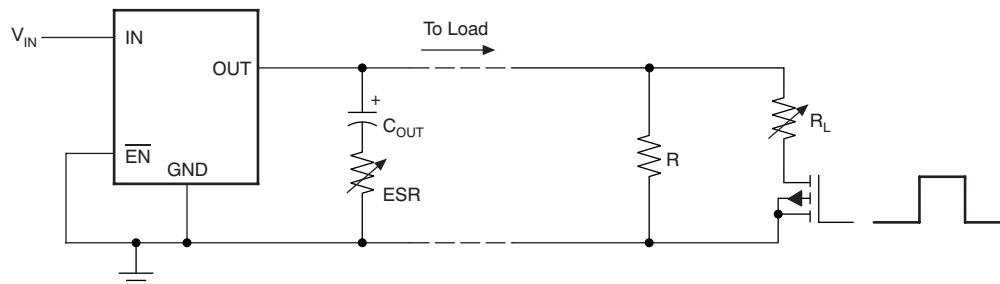
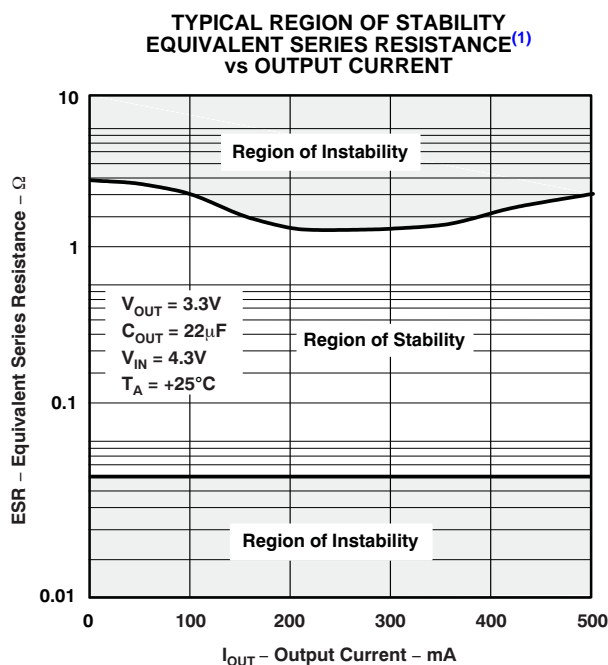
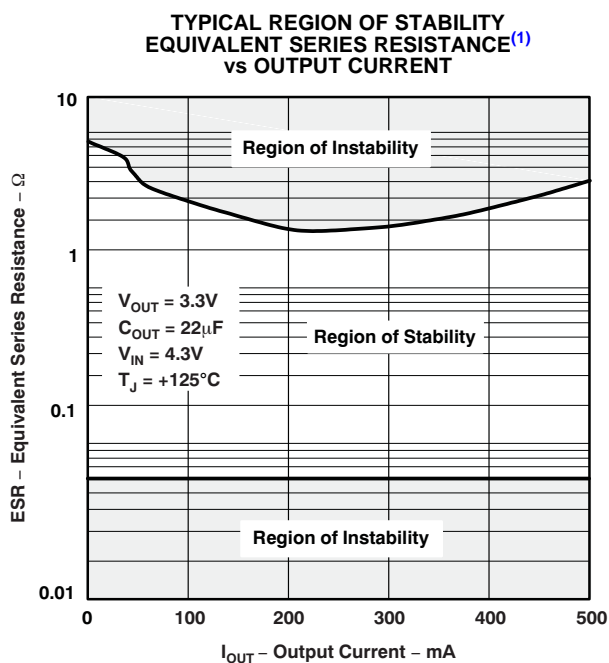


Figure 21.



- (1) Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_{OUT} .

Figure 22.



- (1) Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_{OUT} .

Figure 23.

APPLICATION INFORMATION

The TPS775xx and TPS776xx feature very low quiescent current, which remains virtually constant even with varying loads. Conventional LDO regulators use a pnp pass element, the base current of which is directly proportional to the load current through the regulator ($I_B = I_C/\beta$). The TPS775xx and TPS776xx use a PMOS transistor to pass current; because the gate of the PMOS is voltage driven, operating current is low and invariable over the full load range.

Another pitfall associated with the pnp-pass element is its tendency to saturate when the device goes into dropout. The resulting drop in β forces an increase in I_B to maintain the load. During power up, this I_B increase translates to large start-up currents. Systems with limited supply current may fail to start up. In battery-powered systems, it means rapid battery discharge when the voltage decays below the minimum required for regulation. The TPS775xx and TPS776xx quiescent currents remain low even when the regulator drops out, eliminating both problems.

The TPS775xx and TPS776xx families also feature a shutdown mode that places the output in the high-impedance state (essentially equal to the feedback-divider resistance) and reduces quiescent current to 2 μ A. If the shutdown feature is not used, \overline{EN} should be tied to ground.

Minimum Load Requirements

The TPS775xx and TPS776xx families are stable at zero load; no minimum load is required for operation.

FB—Pin Connection (Adjustable Version Only)

The FB pin is an input pin to sense the output voltage and close the loop for the adjustable option. The output voltage is sensed through a resistor divider network to close the loop as it is shown in Figure 25. Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit to improve performance at that point. Internally, FB connects to a high-impedance wide-bandwidth amplifier and noise pickup feeds through to the regulator output. Routing the FB connection to minimize/avoid noise pickup is essential.

External Capacitor Requirements

An input capacitor is not usually required; however, a ceramic bypass capacitor (0.047 μ F or larger) improves load transient response and noise rejection if the TPS775xx or TPS776xx are located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamperes) load transients with fast rise times are anticipated.

Like all low dropout regulators, the TPS775xx and TPS776xx require an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 10 μ F and the ESR (equivalent series resistance) must be between 50m Ω and 1.5 Ω . Capacitor values 10 μ F or larger are acceptable, provided the ESR is less than 1.5 Ω . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described previously.

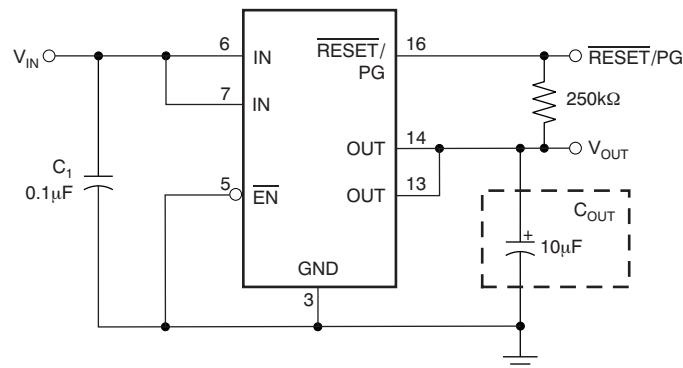


Figure 24. Typical Application Circuit (Fixed Versions)

APPLICATION INFORMATION (continued)**Programming the TPS77x01 Adjustable LDO Regulator**

The output voltage of the TPS77x01 adjustable regulator is programmed using an external resistor divider as shown in [Figure 25](#). The output voltage is calculated using [Equation 1](#):

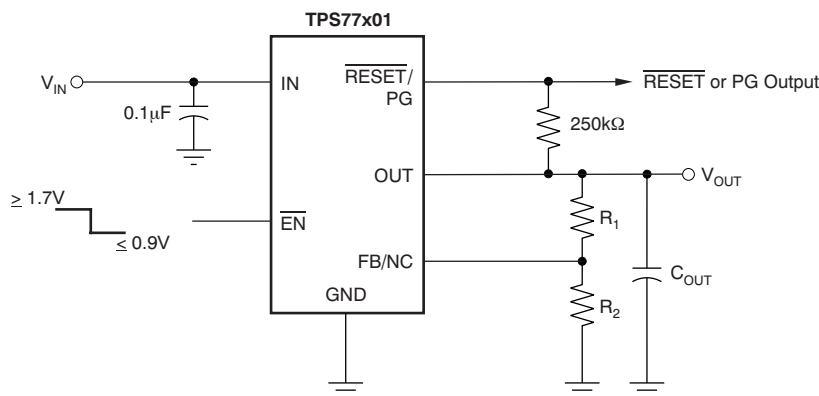
$$V_{OUT} = V_{ref} \times \left(1 + \frac{R_1}{R_2}\right) \quad (1)$$

Where:

- $V_{ref} = 1.1834V$ typ (the internal reference voltage)

Resistors R_1 and R_2 should be chosen for approximately 10µA divider current. Lower value resistors can be used, but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose $R_2 = 110k\Omega$ to set the divider current at approximately 10µA and then calculate R_1 using [Equation 2](#):

$$R_1 = \left(\frac{V_{OUT}}{V_{ref}} - 1\right) \times R_2 \quad (2)$$



**OUTPUT VOLTAGE
PROGRAMMING GUIDE**

OUTPUT VOLTAGE	R_1	R_2	UNIT
2.5V	121	110	kΩ
3.3V	196	110	kΩ
3.6V	226	110	kΩ
4.75V	332	110	kΩ

Figure 25. TPS77x01 Adjustable LDO Regulator Programming

Reset Indicator

The TPS775xx features a \overline{RESET} output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage: when the output drops to between 92% and 98% of its nominal regulated value, the \overline{RESET} output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. \overline{RESET} can be used to drive power-on reset circuitry or as a low-battery indicator. \overline{RESET} does not assert itself when the regulated output voltage falls outside the specified 2% tolerance, but instead reports an output voltage low relative to its nominal regulated value (refer to [Timing Diagram](#) for start-up sequence).

Power-Good Indicator

The TPS776xx features a power-good (PG) output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage: when the output drops to between 92% and 98% of its nominal regulated value, the PG output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. PG can be used to drive power-on reset circuitry or used as a low-battery indicator.

APPLICATION INFORMATION (continued)

Regulator Protection

The TPS775xx and TPS776xx PMOS-pass transistors have a built-in back diode that conducts reverse currents when the input voltage drops below the output voltage (for example, during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS775xx and TPS776xx also feature internal current limiting and thermal protection. During normal operation, the TPS775xx and TPS776xx limit output current to approximately 1.7A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds +150°C(typ), thermal-protection circuitry shuts it down. Once the device has cooled below +130°C(typ), regulator operation resumes.

Power Dissipation and Junction Temperature

Specified regulator operation is assured to a junction temperature of +125°C; the maximum junction temperature should be restricted to +125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_D , which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

where:

- $T_{J(max)}$ is the maximum allowable junction temperature
- $R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package, and is calculated as $\frac{1}{\text{derating factor}}$ from the dissipation rating tables
- T_A is the ambient temperature

The regulator dissipation is calculated using:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT}$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS77501D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77501DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77501DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77501DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77501PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77501PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77501PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77501PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77515D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77515DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77515DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77515DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77515PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77515PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77515PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77515PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77516D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77516DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77516DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77516DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77516PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77516PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77516PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77516PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77518D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS77518DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77518DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77518DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77518PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77518PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77518PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77518PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77525D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77525DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77525DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77525DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77525PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77525PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77525PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77525PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77533D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77533DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77533DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77533DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77533PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77533PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77533PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77533PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77601D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77601DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77601DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS77601DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77601PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77601PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77601PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77601PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77615D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77615DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77615DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77615DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77615PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77615PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77615PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77615PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77618D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77618DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77618DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77618DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77618PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77618PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77618PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77618PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77625D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77625DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77625DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77625DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77625PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS77625PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77625PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77625PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77628D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77628DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77628DRG4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI
TPS77628PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77628PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77628PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77628PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77633D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77633DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77633DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77633DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS77633PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77633PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77633PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS77633PWPRG4	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

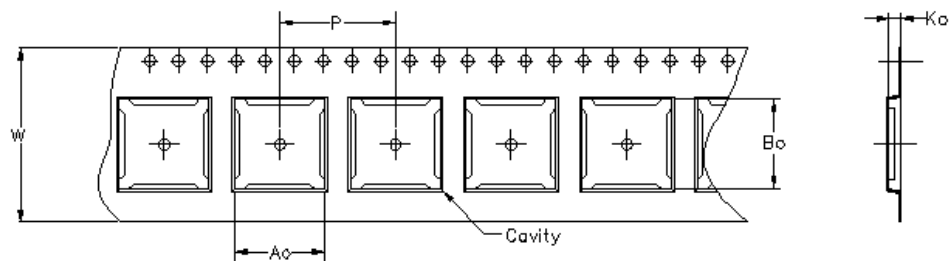
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

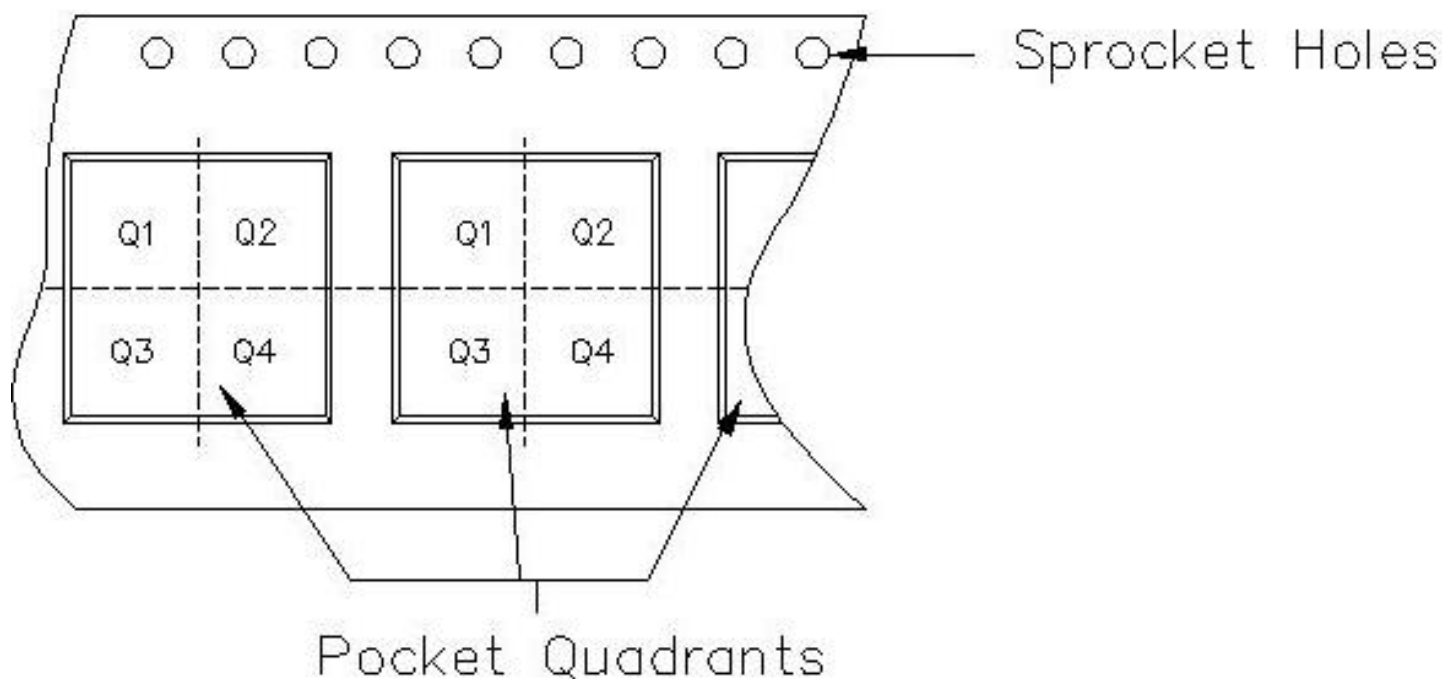
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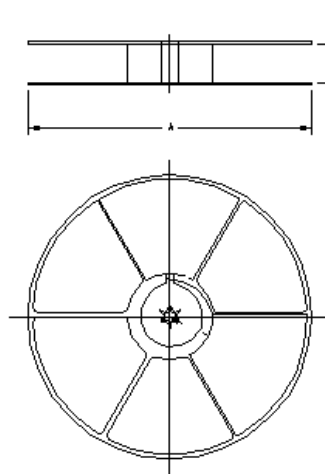
Carrier tape design is defined largely by the component length, width, and thickness.

A_0 = Dimension designed to accommodate the component width.
B_0 = Dimension designed to accommodate the component length.
K_0 = Dimension designed to accommodate the component thickness.
W = Overall width of the carrier tape.
P = Pitch between successive cavity centers.



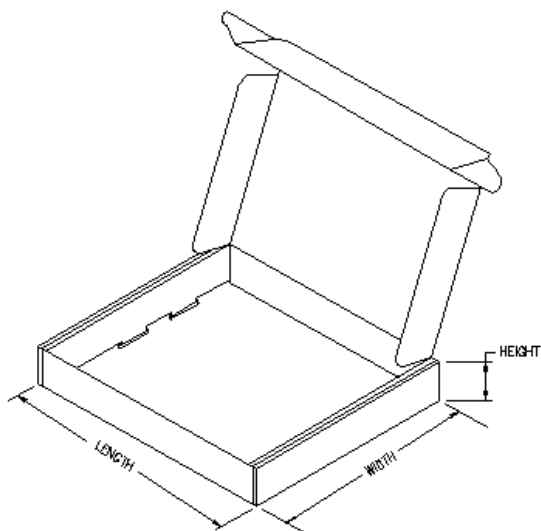
TAPE AND REEL INFORMATION

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS77501DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77501PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77515DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77515PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77516DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77516PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77518DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77518PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77525DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77525PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77533DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77533PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77601DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77601PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77615DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77615PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77618DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77618PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77625DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77625PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77628PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1
TPS77633DR	D	8	TAI	330	12	6.4	5.2	2.1	8	12	Q1
TPS77633PWPR	PWP	20	TAI	330	16	6.95	7.1	1.6	8	16	Q1



TAPE AND REEL BOX INFORMATION

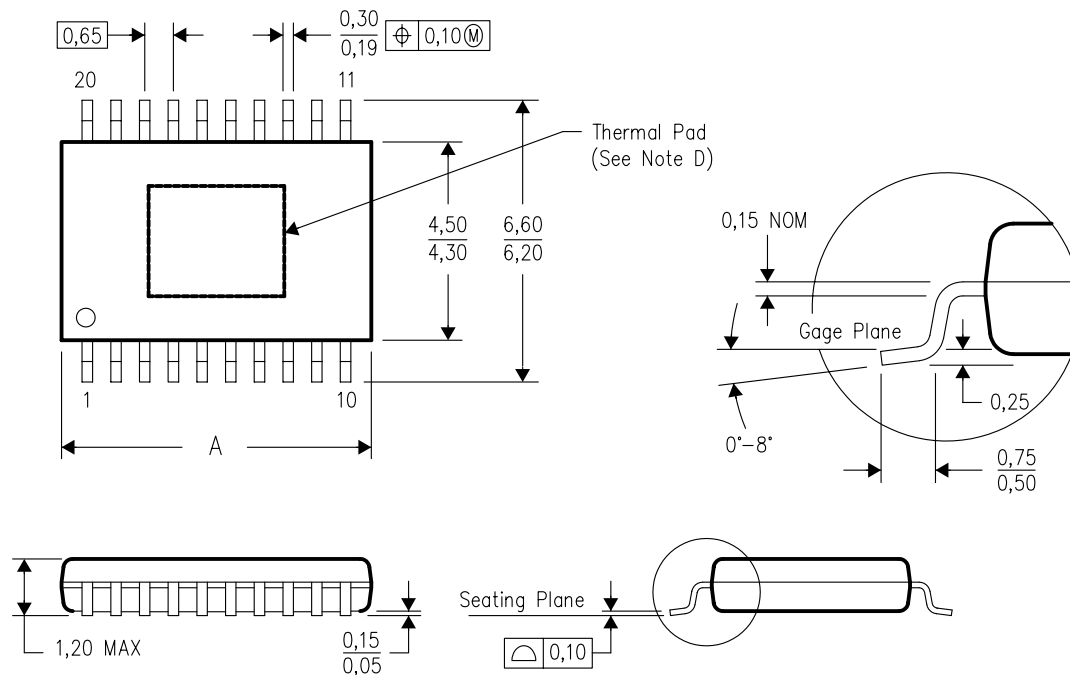
Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
TPS77501DR	D	8	TAI	346.0	346.0	29.0
TPS77501PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77515DR	D	8	TAI	346.0	346.0	29.0
TPS77515PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77516DR	D	8	TAI	346.0	346.0	29.0
TPS77516PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77518DR	D	8	TAI	346.0	346.0	29.0
TPS77518PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77525DR	D	8	TAI	346.0	346.0	29.0
TPS77525PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77533DR	D	8	TAI	346.0	346.0	29.0
TPS77533PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77601DR	D	8	TAI	346.0	346.0	29.0
TPS77601PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77615DR	D	8	TAI	346.0	346.0	29.0
TPS77615PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77618DR	D	8	TAI	346.0	346.0	29.0
TPS77618PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77625DR	D	8	TAI	346.0	346.0	29.0
TPS77625PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77628PWPR	PWP	20	TAI	346.0	346.0	33.0
TPS77633DR	D	8	TAI	346.0	346.0	29.0
TPS77633PWPR	PWP	20	TAI	535.4	346.0	48.3



PWP (R-PDSO-G**)

PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

20 PIN SHOWN



PINS **	14	16	20	24	28
DIM					
A MAX	5,10	5,10	6,60	7,90	9,80
A MIN	4,90	4,90	6,40	7,70	9,60

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- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - Falls within JEDEC MO-153

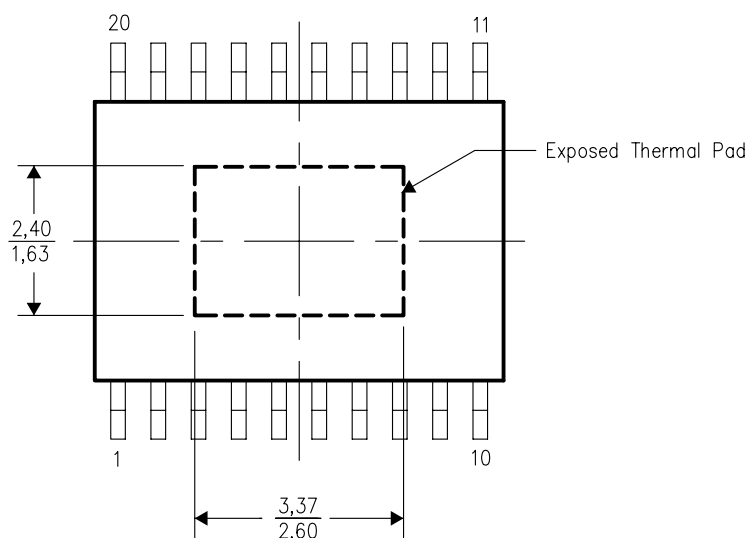
PowerPAD is a trademark of Texas Instruments.

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. When the thermal pad is soldered directly to the printed circuit board (PCB), the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to a ground plane or special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

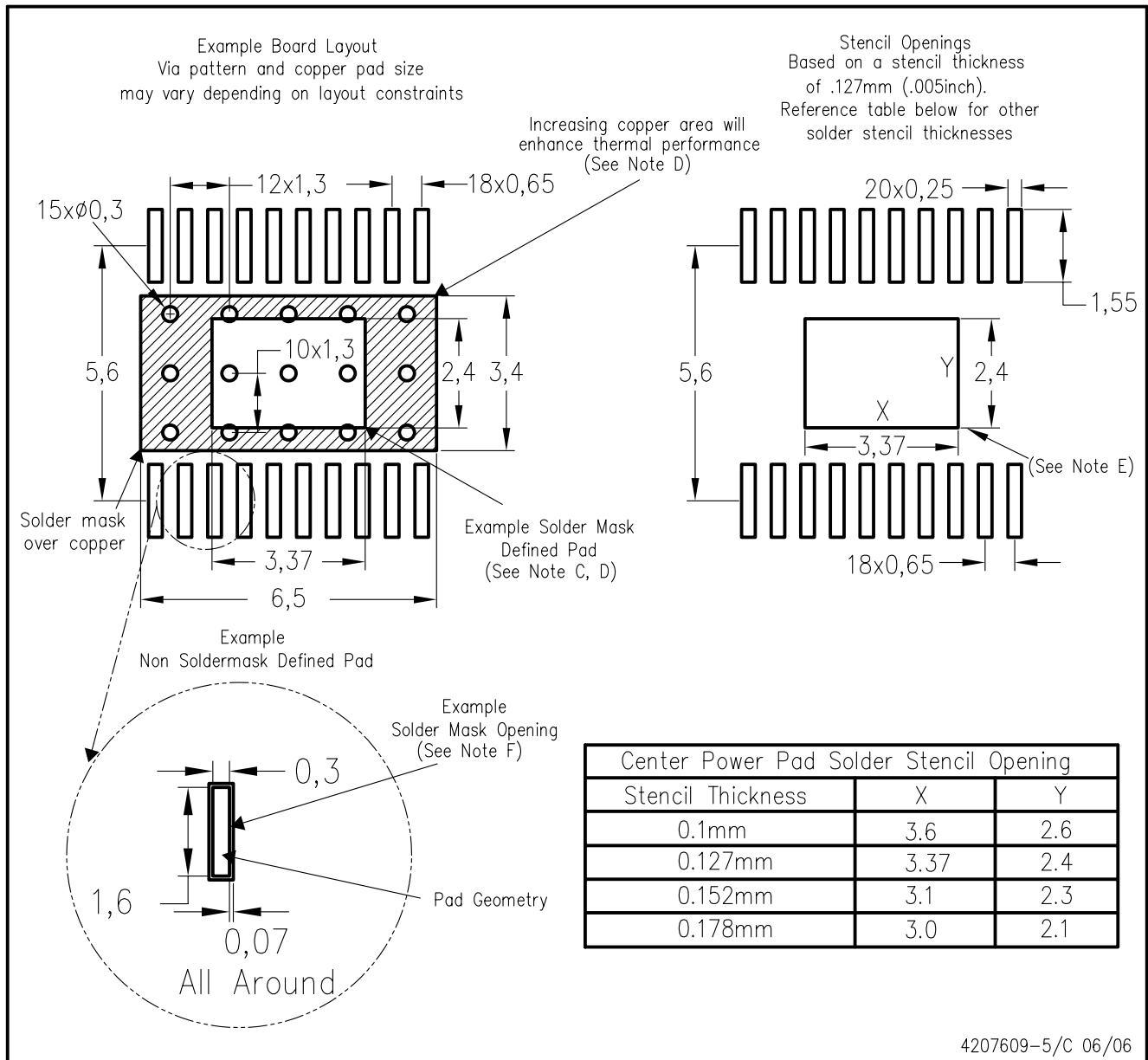


Top View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

PWP (R-PDSO-G20) PowerPAD™

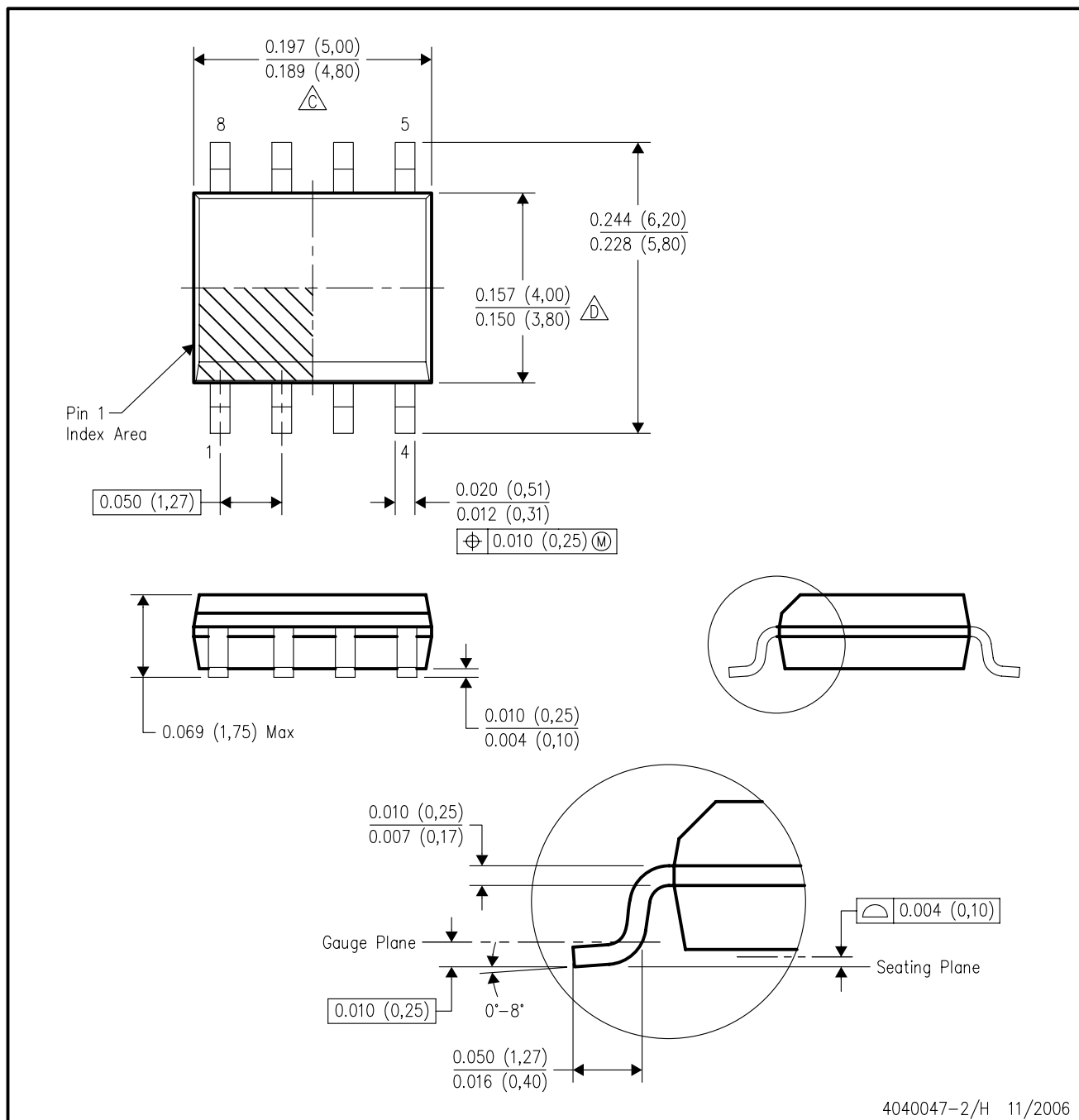


- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>. Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PowerPAD is a trademark of Texas Instruments.

D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
D. Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
E. Reference JEDEC MS-012 variation AA.

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